



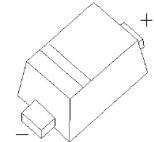
迈拓电子  
MAITUO ELECTRONIC

## 1SS389 SCHOTTKY BARRIER DIODE



### FEATURES

- High Speed
- High Reliability
- Small Package
- Low Forward Voltage



### APPLICATIONS

- High Speed Switching

SOD-523

### MARKING : N

### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted )

Symbol	Parameter	Value	Unit
$V_R$	DC Blocking Voltage	10	V
$I_o$	Continuous Forward Current	100	mA
$I_{FM}$	Peak Forward Current	200	mA
$I_{FSM}$	Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	1	A
$P_D$	Power Dissipation	150	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	667	°C/W
$T_j$	Operating Junction Temperature Range	-40~+125	°C
$T_{stg}$	Storage Temperature Range	-55~+150	°C

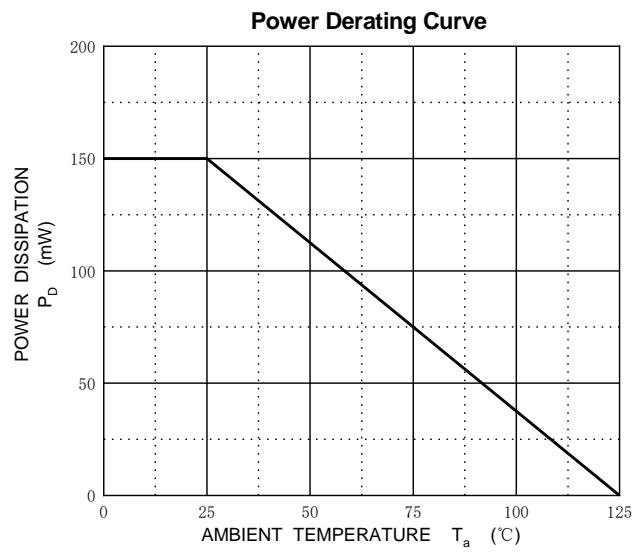
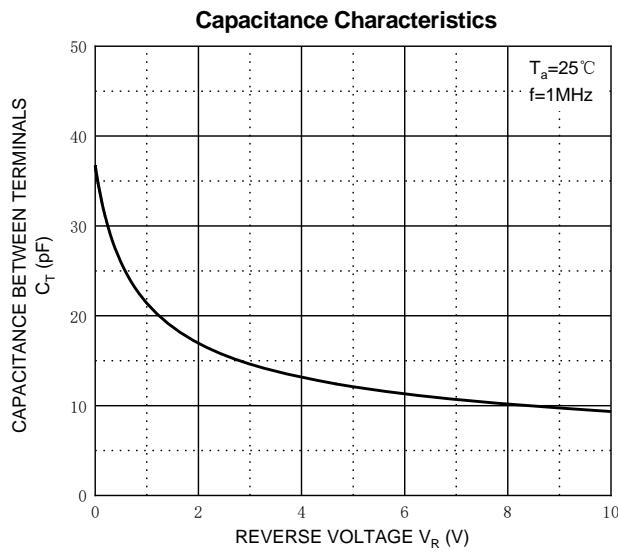
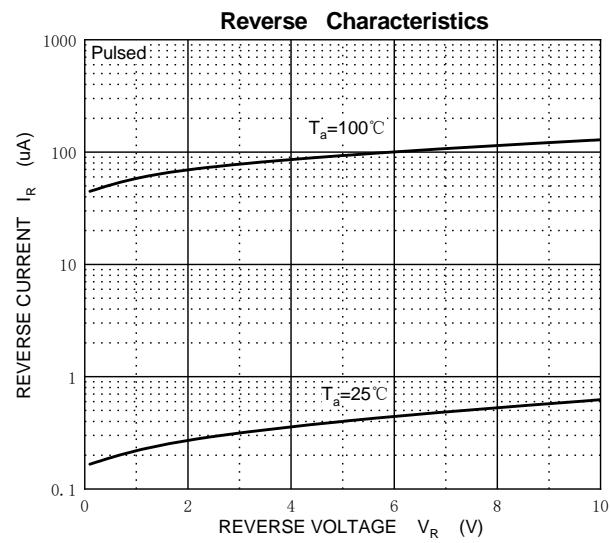
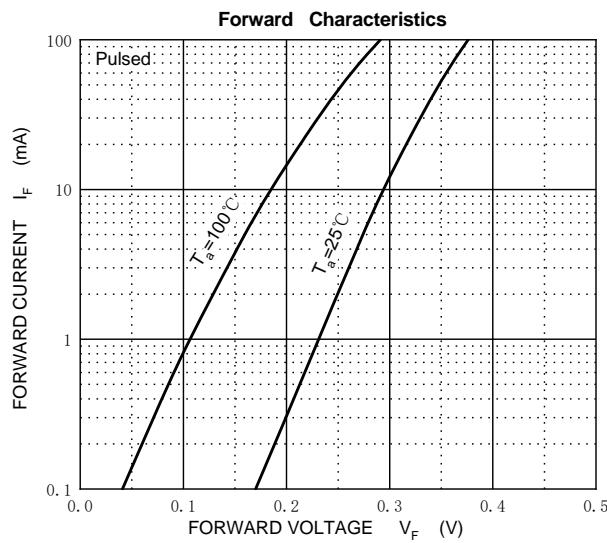
### ELECTRICAL CHARACTERISTICS( $T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	10			V
Reverse current	$I_R$	$V_R=10\text{V}$			20	$\mu\text{A}$
Forward voltage	$V_F$	$I_F=1\text{mA}$		0.18		V
		$I_F=5\text{mA}$			0.3	
		$I_F=100\text{mA}$			0.5	
Total capacitance	$C_{tot}$	$V_R=0\text{V}, f=1\text{MHz}$			40	pF



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## Typical Characteristics



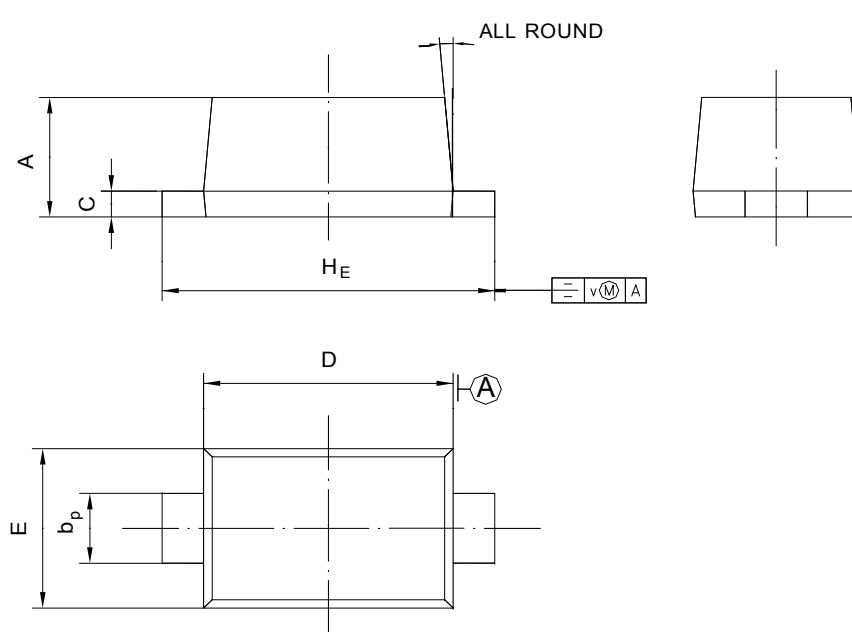


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## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	$b_p$	C	D	E	$H_E$	V	$\angle$
mm	0.68 0.58	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°